

### **FEATURES**

- Member of the Texas Instruments Widebus™
   Family
- EPIC™ (Enhanced-Performance Implanted CMOS) Submicron Process
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Package Options Include Plastic 300-mil Shrink Small-Outline (DL) and Thin Shrink Small-Outline (DGG) Packages

#### DESCRIPTION

This 18-bit buffer and line driver is designed for 1.65-V to 3.6-V  $V_{\rm CC}$  operation.

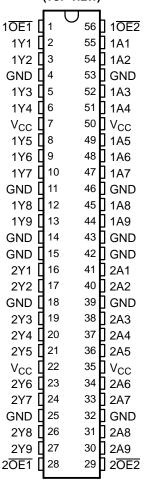
This SN74ALVCH16825 improves the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters.

The device can be used as two 9-bit buffers or one 18-bit buffer. It provides true data.

The 3-state control gate is a 2-input AND gate with active-low inputs so that if either output-enable (OE1 or OE2) input is high, all nine affected outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

# DGG OR DL PACKAGE (TOP VIEW)



Active bus-hold circuitry is provided to hold unused or floating inputs at a valid logic level.

The SN74ALVCH16825 is characterized for operation from -40°C to 85°C.

# FUNCTION TABLE (each 9-bit section)

	INPUTS		OUTPUT
OE1	OE2	Α	Y
L	L	L	L
L	L	Н	Н
Н	X	Χ	Z
X	Н	Χ	Z



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

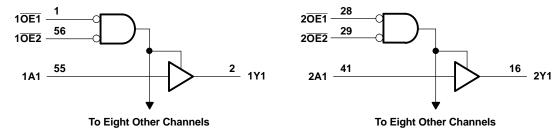
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#### LOGIC SYMBOL<sup>(1)</sup> & 10E1 EN1 56 10E2 28 20E1 & 29 EN2 2<u>0E2</u> 55 2 1A1 1 ▽ 1Y1 3 54 1Y2 1A2 52 5 1Y3 1A3 51 6 1Y4 1A4 8 49 1A5 1Y5 48 9 1A6 1Y6 47 10 1Y7 1A7 45 12 1Y8 1A8 44 13 1Y9 1A9 41 16 2A1 2 ▽ 2Y1 17 2A2 2Y2 38 19 2A2 2Y3 37 20 2A3 2Y4 36 21 2Y5 2A4 34 23 2A5 2Y6 33 24 2A6 2Y7 31 26 2Y8 2A7 30 2A8 2Y9

(1) This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

### **LOGIC DIAGRAM (POSITIVE LOGIC)**





### SN74ALVCH16825 18-BIT BUFFER/DRIVER WITH 3-STATE OUTPUTS

### ABSOLUTE MAXIMUM RATINGS(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
$V_{CC}$	Supply voltage range		-0.5	4.6	V
VI	Input voltage range <sup>(2)</sup>	-0.5	4.6	V	
Vo	Output voltage range <sup>(2)(3)</sup>	-0.5	V <sub>CC</sub> + 0.5	V	
I <sub>IK</sub>	Input clamp current	V <sub>I</sub> < 0		-50	mA
I <sub>OK</sub>	Output clamp current		-50	mA	
Io	Continuous output current			±50	mA
	Continuous current through each V <sub>CC</sub> or GND			±100	mA
0	Declare the second instruction of (4)	DGG package		81	°C/W
$\theta_{JA}$	Package thermal impedance <sup>(4)</sup>	DL package		74	C/VV
T <sub>stg</sub>	Storage temperature range		-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### **RECOMMENDED OPERATING CONDITIONS**(1)

			MIN	MAX	UNIT	
$V_{CC}$	Supply voltage		1.65	3.6	V	
		V <sub>CC</sub> = 1.65 V to 1.95 V	0.65 × V <sub>CC</sub>			
$V_{IH}$	High-level input voltage	V <sub>CC</sub> = 2.3 V to 2.7 V	1.7		V	
		V <sub>CC</sub> = 2.7 V to 3.6 V	2			
		V <sub>CC</sub> = 1.65 V to 1.95 V		$0.35 \times V_{CC}$		
$V_{IL}$	Low-level input voltage	V <sub>CC</sub> = 2.3 V to 2.7 V		0.7	V	
		V <sub>CC</sub> = 2.7 V to 3.6 V		8.0		
VI	Input voltage		0	V <sub>CC</sub>	V	
Vo	Output voltage		0	V <sub>CC</sub>	V	
		V <sub>CC</sub> = 1.65 V		-4		
	High-level output current	V <sub>CC</sub> = 2.3 V		-12	mA	
I <sub>OH</sub>		V <sub>CC</sub> = 2.7 V		-12		
		V <sub>CC</sub> = 3 V		-24		
		V <sub>CC</sub> = 1.65 V		4		
	Lave lavel autout aumant	V <sub>CC</sub> = 2.3 V		12	A	
l <sub>OL</sub>	Low-level output current	V <sub>CC</sub> = 2.7 V		12	_	
		V <sub>CC</sub> = 3 V		24		
Δt/Δν	Input transition rise or fall rate			10	ns/V	
T <sub>A</sub>	Operating free-air temperature		-40	85	°C	

<sup>(1)</sup> All unused control inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

<sup>(2)</sup> The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>(3)</sup> This value is limited to 4.6 V maximum.

<sup>(4)</sup> The package thermal impedance is calculated in accordance with JESD 51.

SCES039D-JULY 1995-REVISED OCTOBER 2004



### **ELECTRICAL CHARACTERISTICS**

over recommended operating free-air temperature range (unless otherwise noted)

P	ARAMETER	TEST CONDITIONS	V <sub>cc</sub>	MIN TYP(1)	MAX	UNIT		
		I <sub>OH</sub> = -100 μA	1.65 V to 3.6 V	V <sub>CC</sub> - 0.2				
		I <sub>OH</sub> = -4 mA	1.65 V	1.2				
		I <sub>OH</sub> = -6 mA	2.3 V	2				
$V_{OH}$			2.3 V	1.7		V		
		I <sub>OH</sub> = -12 mA	2.7 V	2.2				
			3 V	2.4				
		I <sub>OH</sub> = -24 mA	3 V	2				
		I <sub>OL</sub> = 100 μA	1.65 V to 3.6 V		0.2			
		I <sub>OL</sub> = 4 mA	1.65 V		0.45			
.,		I <sub>OL</sub> = 6 mA	2.3 V		0.4	\ /		
V <sub>OL</sub>	V <sub>OL</sub>	10	2.3 V		0.7	V		
		I <sub>OL</sub> = 12 mA	2.7 V		0.4			
		I <sub>OL</sub> = 24 mA	3 V		0.55			
I <sub>I</sub>		$V_I = V_{CC}$ or GND	3.6 V		±5	μΑ		
		V <sub>I</sub> = 0.58 V	1.65 V	25				
		V <sub>I</sub> = 1.07 V	1.65 V	-25				
		V <sub>I</sub> = 0.7 V	2.3 V	45				
I <sub>I(hold)</sub>	)	V <sub>I</sub> = 1.7 V	2.3 V	-45		μΑ		
, ,	,	V <sub>I</sub> = 0.8 V	3 V	75				
		V <sub>I</sub> = 2 V	3 V	-75				
		V <sub>I</sub> = 0 to 3.6 V <sup>(2)</sup>	3.6 V		±500			
I <sub>OZ</sub>		$V_O = V_{CC}$ or GND	3.6 V		±10	μΑ		
I <sub>CC</sub>		$V_I = V_{CC}$ or GND $I_O = 0$	3.6 V		40	μΑ		
$\Delta I_{CC}$		One input at V <sub>CC</sub> - 0.6 V, Other inputs at V <sub>CC</sub> or GND	3 V to 3.6 V		750	μΑ		
	Control inputs	V V SECULO	0.01/	3.5		pF		
Ci	Data inputs	$V_I = V_{CC}$ or GND	3.3 V	6	6			
Co	Outputs	$V_O = V_{CC}$ or GND	3.3 V	7.5		pF		

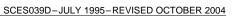
### **SWITCHING CHARACTERISTICS**

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1 through Figure 3)

PARAM	PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 1.8 V	V <sub>CC</sub> = 2 ± 0.2	2.5 V : V	V <sub>CC</sub> = 2	2.7 V	V <sub>CC</sub> = 3 ± 0.3	3.3 V V	UNIT
		(INPOT)	(0011-01)	TYP	MIN	MAX	MIN	MAX	MIN	MAX	
t <sub>po</sub>	I	А	Y	(1)	1	4.1		3.9	1	3.4	ns
t <sub>en</sub>	1	ŌĒ	Y	(1)	1	6		5.7	1	4.7	ns
t <sub>dis</sub>	6	ŌĒ	Υ	(1)	1.2	5.6		4.9	1.3	4.5	ns

<sup>(1)</sup> This information was not available at the time of publication.

All typical values are at  $V_{CC} = 3.3 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ . This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to





### **OPERATING CHARACTERISTICS**

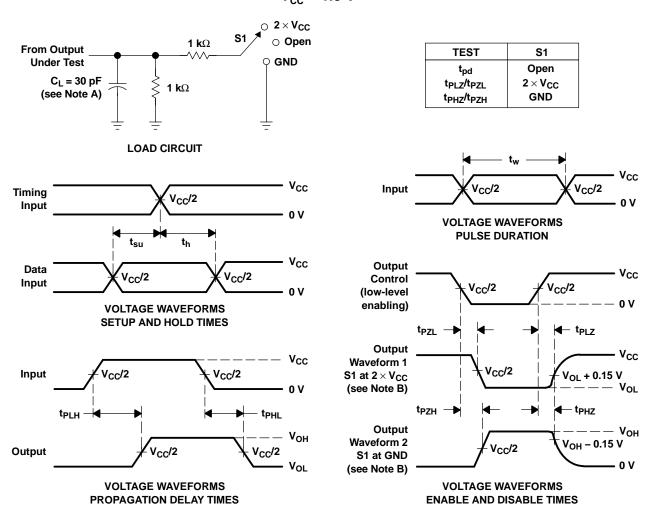
 $T_A = 25^{\circ}C$ 

	PARAMETE	R	TEST CONDITIONS	V <sub>CC</sub> = 1.8 V TYP	V <sub>CC</sub> = 2.5 V TYP	V <sub>CC</sub> = 3.3 V TYP	UNIT
C	Power dissipation	Outputs enabled	C <sub>1</sub> = 50 pF. f = 10 MHz	(1)	16	18	nE
$C_{pd}$	capacitance	Outputs disabled	$C_L = 50 \text{ pF},  f = 10 \text{ MHz}$	(1)	4	6	p⊦

<sup>(1)</sup> This information was not available at the time of publication.



# PARAMETER MEASUREMENT INFORMATION $V_{cc} = 1.8 \text{ V}$



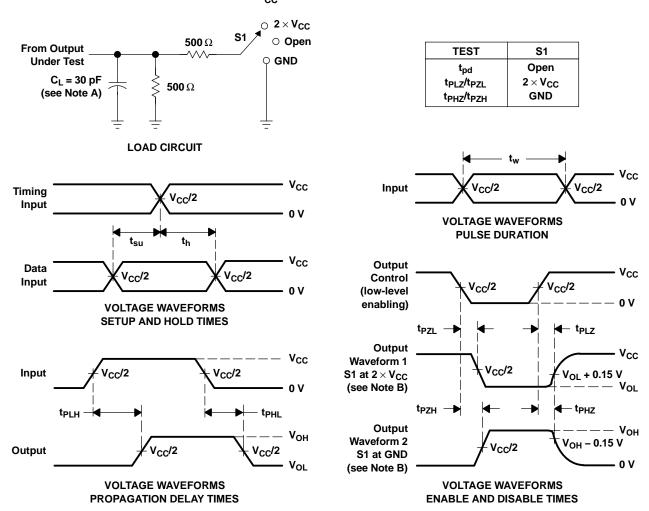
NOTES: A. C<sub>1</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR $\le$ 10 MHz,  $Z_0 = 50 \Omega$ ,  $t_f \le 2$  ns.  $t_f \le 2$  ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t<sub>PL7</sub> and t<sub>PH7</sub> are the same as t<sub>dis</sub>.
- F. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.
- G. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>pd</sub>.

Figure 1. Load Circuit and Voltage Waveforms



# PARAMETER MEASUREMENT INFORMATION $V_{\rm CC}$ = 2.5 V $\pm$ 0.2 V



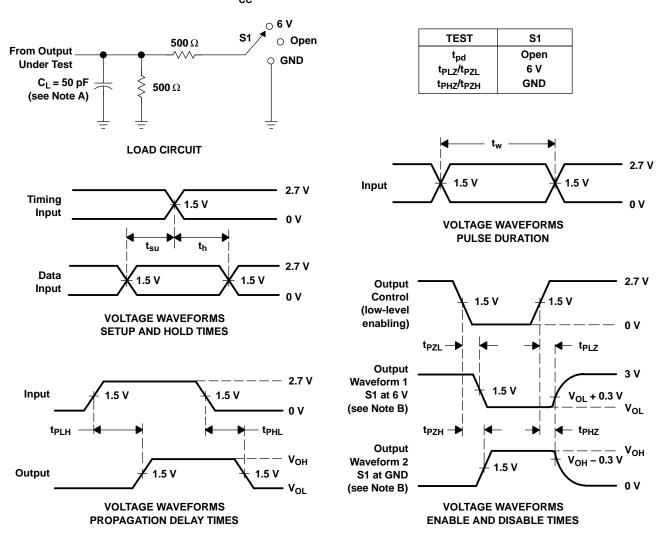
NOTES: A. C<sub>1</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z  $_{O}$  = 50  $\Omega$ ,  $t_{f}$   $\leq$  2 ns,  $t_{f}$   $\leq$  2 ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t<sub>PL7</sub> and t<sub>PH7</sub> are the same as t<sub>dis</sub>.
- F. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.
- G. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>pd</sub>.

Figure 2. Load Circuit and Voltage Waveforms



# PARAMETER MEASUREMENT INFORMATION $V_{CC}$ = 2.7 V AND 3.3 V $\pm$ 0.3 V



- NOTES: A. C<sub>L</sub> includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_0$  = 50  $\Omega$ ,  $t_r \leq$  2.5 ns,  $t_f \leq$  2.5 ns.
  - D. The outputs are measured one at a time, with one transition per measurement.
  - E. t<sub>PLZ</sub> and t<sub>PHZ</sub> are the same as t<sub>dis</sub>.
  - F. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.
  - G. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>pd</sub>.

Figure 3. Load Circuit and Voltage Waveforms



### PACKAGE OPTION ADDENDUM

10-Dec-2020

#### PACKAGING INFORMATION

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Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN74ALVCH16825DGGR	ACTIVE	TSSOP	DGG	56	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVCH16825	Samples
SN74ALVCH16825DL	ACTIVE	SSOP	DL	56	20	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVCH16825	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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10-Dec-2020

### PACKAGE MATERIALS INFORMATION

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### TAPE AND REEL INFORMATION





_		
		Dimension designed to accommodate the component width
	B0	Dimension designed to accommodate the component length
	K0	Dimension designed to accommodate the component thickness
	W	Overall width of the carrier tape
ı	P1	Pitch between successive cavity centers

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74ALVCH16825DGGR	TSSOP	DGG	56	2000	330.0	24.4	8.6	15.6	1.8	12.0	24.0	Q1

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#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
SN74ALVCH16825DGGR	TSSOP	DGG	56	2000	367.0	367.0	45.0	

## DL (R-PDSO-G56)

### PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MO-118

PowerPAD is a trademark of Texas Instruments.





SMALL OUTLINE PACKAGE



#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
  4. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



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